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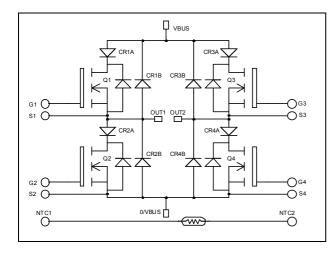






Full bridge Series & parallel diodes MOSFET Power Module

$$\begin{split} V_{DSS} &= 200V \\ R_{DSon} &= 20 m \Omega \text{ typ @ Tj} = 25^{\circ} C \\ I_D &= 89 A \text{ @ Tc} = 25^{\circ} C \end{split}$$



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O/VBUS

Application

- Motor control
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

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S3

Symbol	Parameter		Max ratings	Unit	
$V_{ m DSS}$	Drain - Source Breakdown Voltage		200	V	
Ţ	Continuous Drain Current		89		
I_D	Continuous Drain Current	$T_c = 80$ °C	66	A	
I_{DM}	Pulsed Drain current		356		
V_{GS}	Gate - Source Voltage		±30	V	
R_{DSon}	Drain - Source ON Resistance		24	mΩ	
P_{D}	Maximum Power Dissipation $T_c = 25$ °C		357	W	
I_{AR}	Avalanche current (repetitive and non repetitive)		89	A	
E _{AR}	Repetitive Avalanche Energy		50	mJ	
E_{AS}	Single Pulse Avalanche Energy		2500	1113	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$	C		100	μА
		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}$	С		500	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 44.5A$		20	24	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 2.5 \text{mA}$	3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		6850		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		2180		pF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		97		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		112		
$Q_{\rm gs}$	Gate – Source Charge	$V_{Bus} = 100V$		43		nC
Q_{gd}	Gate – Drain Charge	$I_D = 75A$		47		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		28		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$ $V_{GS} = 122V$		56		
$T_{d(off)}$	Turn-off Delay Time	$\begin{cases} V_{\text{Bus}} = 133V \\ I_{\text{D}} = 75A \end{cases}$		81		ns
T_{f}	Fall Time	$R_G = 5\Omega$		99		
E_{on}	Turn-on Switching Energy	Inductive switching @ 25°C		463		т
E_{off}	Turn-off Switching Energy	$I_{D} = 75A, R_{G} = 133V$		455		μJ
E_{on}	Turn-on Switching Energy	Inductive switching @ 125°C		608		Т
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 75A, R_G = 5\Omega$		531		μJ

Diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =200V	$T_{j} = 25^{\circ}C$ $T_{i} = 125^{\circ}C$			250 500	μΑ
I_{F}	DC Forward Current		$T_c = 85^{\circ}C$		30		A
	Diode Forward Voltage	$I_F = 30A$			1.1	1.15	
V_{F}		$I_F = 60A$			1.4		V
		$I_F = 30A$	$T_j = 125$ °C		0.9		
+	Reverse Recovery Time		$T_j = 25$ °C		24		ns
t_{rr}	Reverse Recovery Time	$I_F = 30A$ $V_R = 133V$	$T_{j} = 125^{\circ}C$		48		115
Q _{rr}	Reverse Recovery Charge	$di/dt = 200A/\mu s$	$T_j = 25$ °C		33		nC
			$T_{j} = 125^{\circ}C$		150		пс



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		Transistor			0.35	°C/W
KthJC			Diode			1.2	C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range -40					150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight		·			160	g

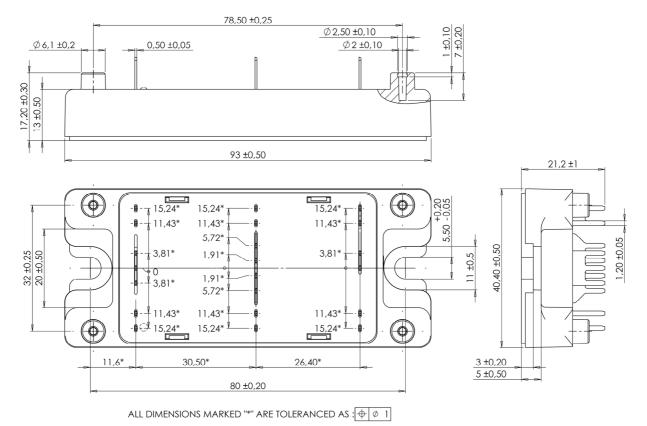
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

SP4 Package outline (dimensions in mm)

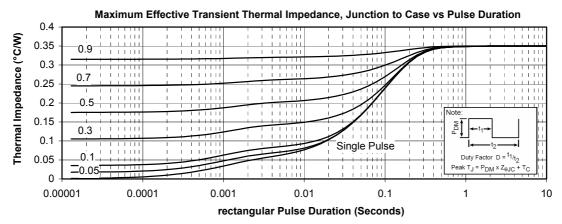


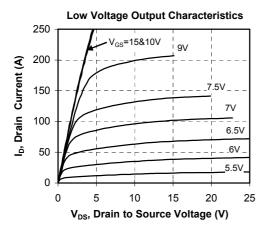
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

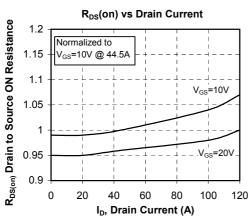
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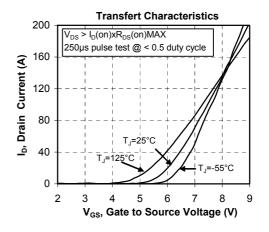


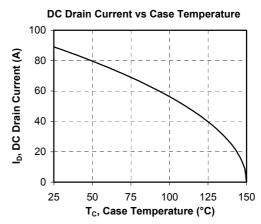
Typical Performance Curve



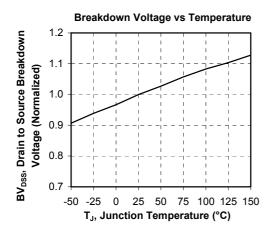


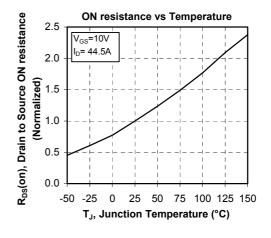


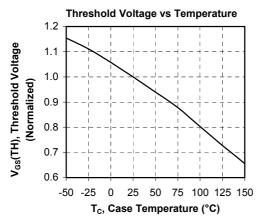


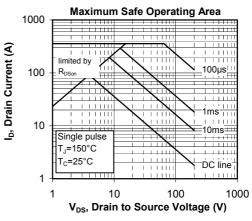


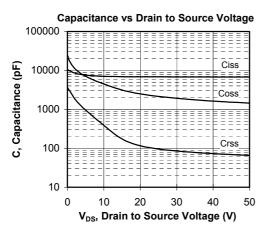


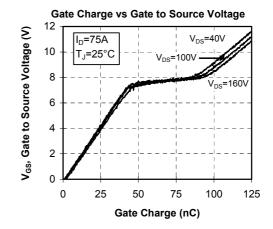




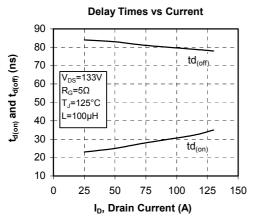


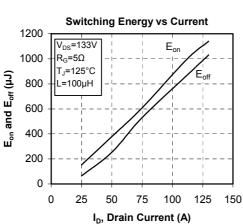


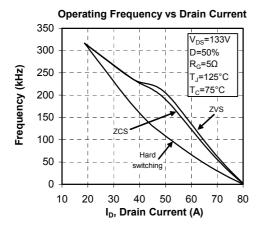


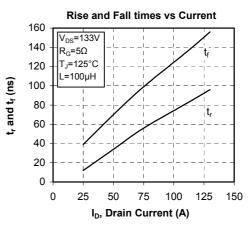


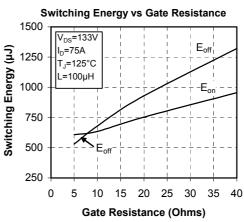


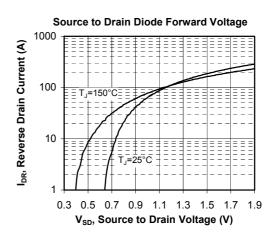














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